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FDS8949_F085

Dual N-Channel Logic Level PowerTrench® MOSFET

40V, 6A, 29mΩ

Features

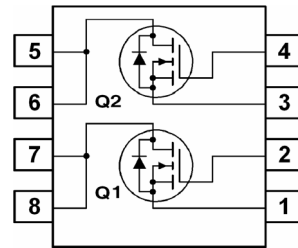
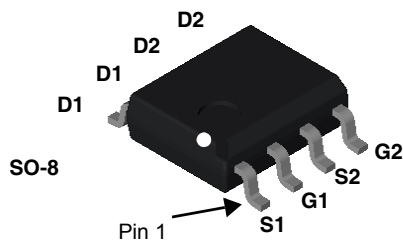
- Max $r_{DS(on)}$ = 29mΩ at $V_{GS} = 10V$
- Max $r_{DS(on)}$ = 36mΩ at $V_{GS} = 4.5V$
- Low gate charge
- High performance trench technology for extremely low $r_{DS(on)}$
- High power and current handling capability
- Qualified to AEC Q101
- RoHS compliant

General Description

These N-Channel Logic Level MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench® process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance. These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.

Applications

- Inverter
- Power suppliers



MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DS}	Drain to Source Voltage	40	V
V_{GS}	Gate to Source Voltage	± 20	V
I_D	Drain Current -Continuous (Note 1a)	6	A
	-Pulsed	20	
E_{AS}	Drain-Source Avalanche Energy (Note 3)	26	mJ
P_D	Power Dissipation for Dual Operation	2	W
	Power Dissipation for Single Operation (Note 1a)	1.6	
	(Note 1b)	0.9	
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	$^\circ\text{C}$

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance-Single operation, Junction to Ambient (Note 1a)	81	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance-Single operation, Junction to Ambient (Note 1b)	135	
$R_{\theta JC}$	Thermal Resistance, Junction to Case (Note 1)	40	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
FDS8949	FDS8949_F085	13"	12mm	2500 units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}, V_{GS} = 0\text{V}$	40			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$, referenced to 25°C		33		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 32\text{V}, V_{GS} = 0\text{V}$ $T_J = 55^\circ\text{C}$			1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$			± 100	nA

On Characteristics (Note 2)

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	1	1.9	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$, referenced to 25°C		-4.6		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 10\text{V}, I_D = 6\text{A}$		21	29	m Ω
		$V_{GS} = 4.5\text{V}, I_D = 4.5\text{A}$		26	36	
		$V_{GS} = 10\text{V}, I_D = 6\text{A}, T_J = 125^\circ\text{C}$		29	43	
g_{FS}	Forward Transconductance	$V_{DS} = 10\text{V}, I_D = 6\text{A}$		22		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V},$ $f = 1\text{MHz}$		715	955	pF
C_{oss}	Output Capacitance			105	140	pF
C_{rss}	Reverse Transfer Capacitance			60	90	pF
R_g	Gate Resistance		$f = 1\text{MHz}$		1.1	

Switching Characteristics

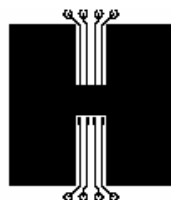
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 20\text{V}, I_D = 1\text{A}$ $V_{GS} = 10\text{V}, R_{GEN} = 6\Omega$		9	18	ns
t_r	Rise Time			5	10	ns
$t_{d(off)}$	Turn-Off Delay Time			23	37	ns
t_f	Fall Time			3	6	ns
Q_g	Total Gate Charge			7.7	11	nC
Q_{gs}	Gate to Source Gate Charge	$V_{DS} = 20\text{V}, I_D = 6\text{A}, V_{GS} = 5\text{V}$		2.4		nC
Q_{gd}	Gate to Drain "Miller" Charge			2.8		nC

Drain-Source Diode Characteristics and Maximum Ratings

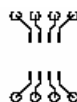
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{V}, I_S = 6\text{A}$ (note 2)		0.8	1.2	V
t_{rr}	Reverse Recovery Time (note 3)	$I_F = 6\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$		17	26	ns
Q_{rr}	Reverse Recovery Charge			7	11	nC

Notes:

1: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.



a) $81^\circ\text{C}/\text{W}$ when mounted on a 1in^2 pad of 2 oz copper



b) $135^\circ\text{C}/\text{W}$ when mounted on a minimum pad.

Scale 1:1 on letter size paper

2: Pulse Test: Pulse Width < 300 us, Duty Cycle < 2.0%.

3: Starting $T_J = 25^\circ\text{C}$, $L = 1\text{mH}$, $I_{AS} = 7.3\text{A}$, $V_{DD} = 40\text{V}$, $V_{GS} = 10\text{V}$.

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

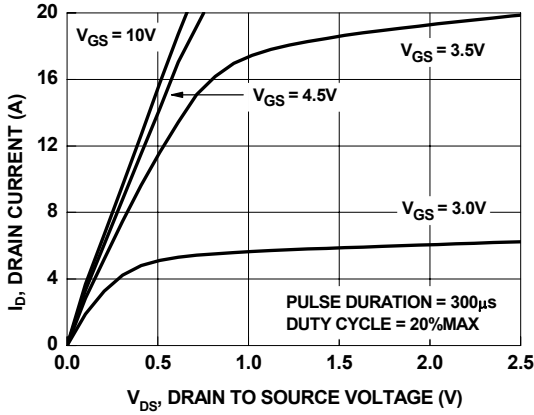


Figure 1. On Region Characteristics

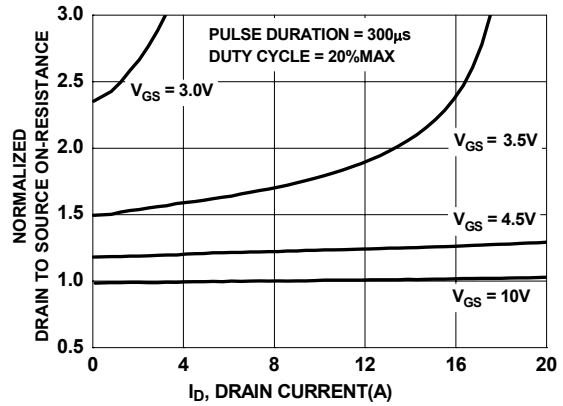


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

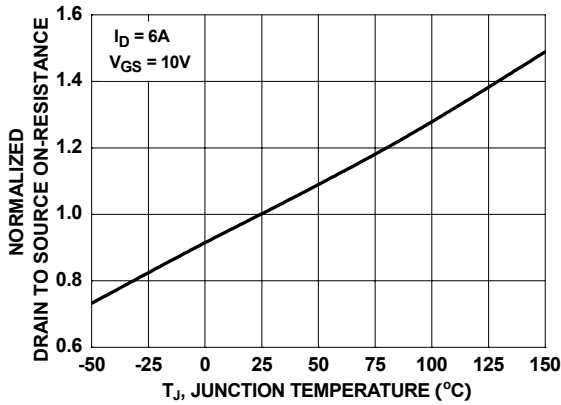


Figure 3. Normalized On Resistance vs Junction Temperature

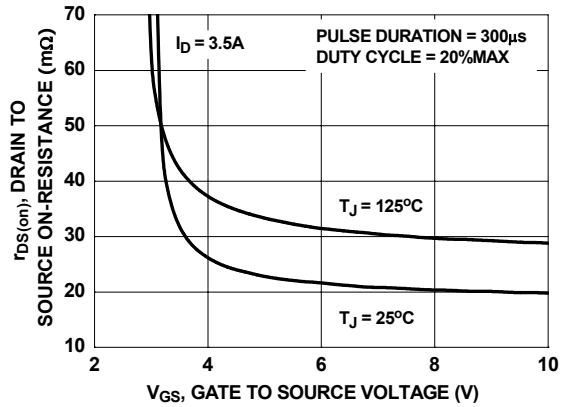


Figure 4. On-Resistance vs Gate to Source Voltage

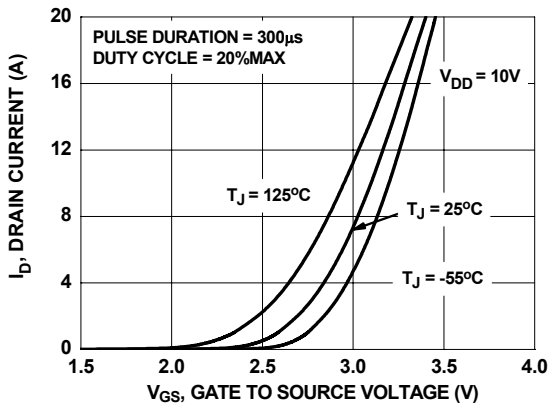


Figure 5. Transfer Characteristics

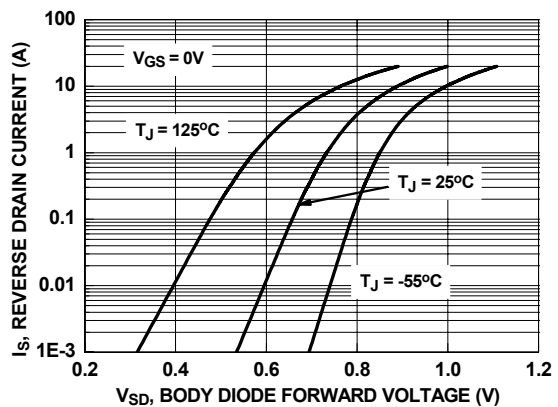


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

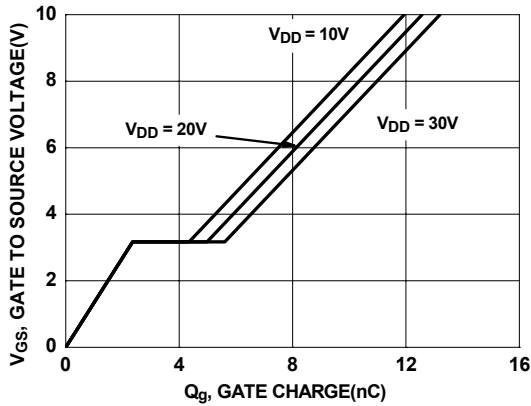


Figure 7. Gate Charge Characteristics

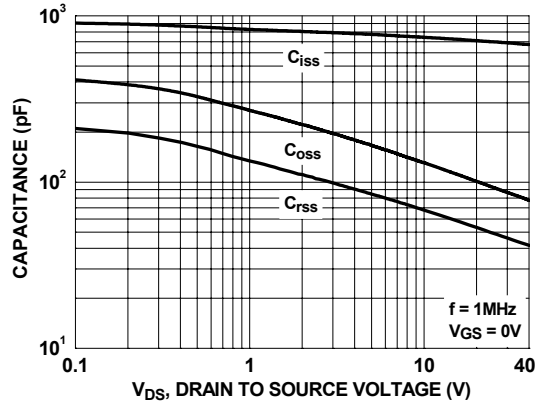


Figure 8. Capacitance vs Drain to Source Voltage

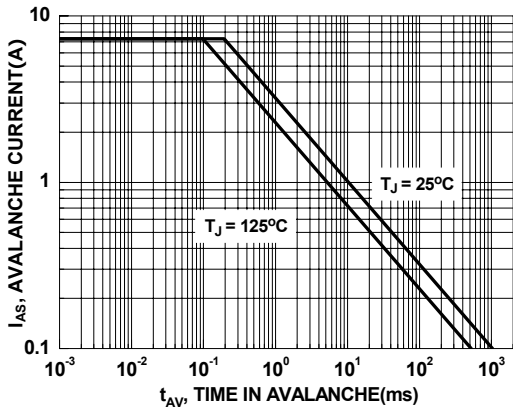


Figure 9. Unclamped Inductive Switching Capability

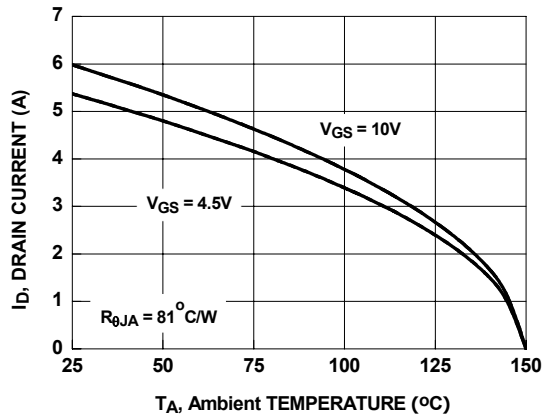


Figure 10. Maximum Continuous Drain Current vs Ambient Temperature

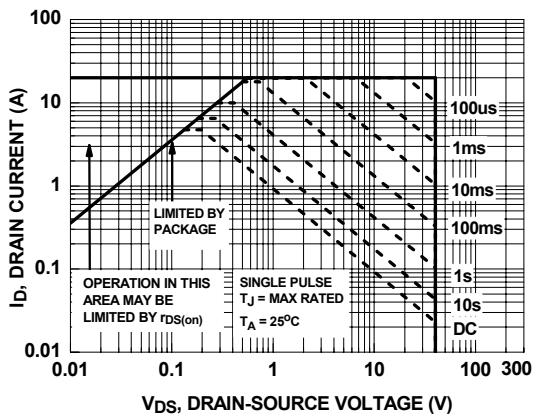


Figure 11. Forward Bias Safe Operating Area

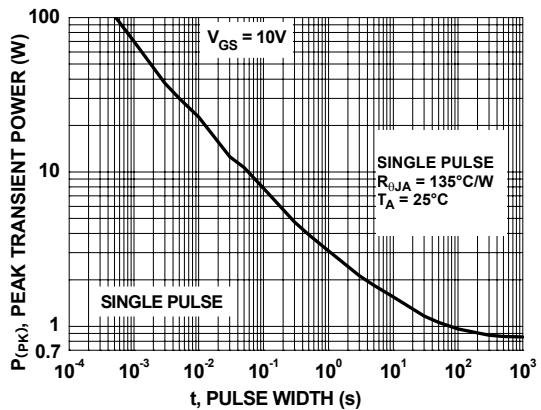


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

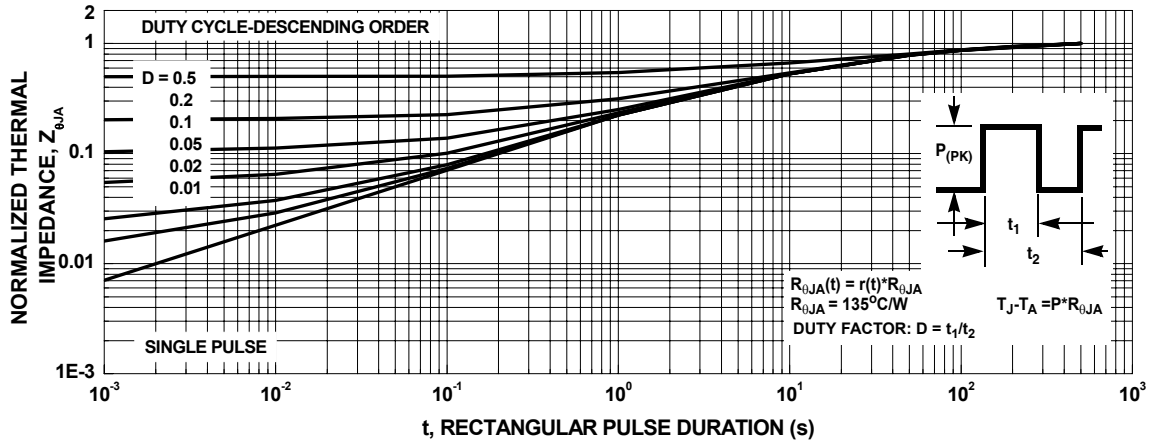



Figure 13. Transient Thermal Response Curve



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